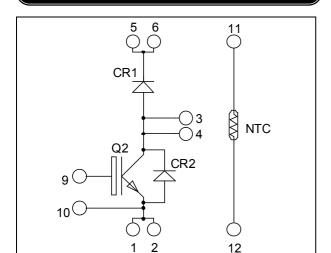
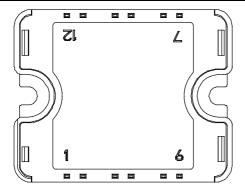


## Boost chopper Trench + Field Stop IGBT3 Power Module





Pins 1/2; 3/4; 5/6 must be shorted together

# $V_{CES} = 1700V$ $I_C = 75A$ @ Tc = 80°C

#### **Application**

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

#### **Features**

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration

### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1700	V
Ţ	Continuous Colloctor Current	$T_C = 25^{\circ}C$	130	
$I_{C}$	Continuous Collector Current		75	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	150	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Maximum Power Dissipation	$T_C = 25^{\circ}C$	465	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	150A @ 1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



## All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				250	μA
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		2.0	2.4	V
$V_{CE(sat)}$		$I_C = 75A$ $T_j = 125^{\circ}$	$T_{j} = 125^{\circ}C$		2.4		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 1 \text{mA}$		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		6800		
$C_{oes}$	Output Capacitance	$V_{CE} = 25V$		277		pF
$C_{res}$	Reverse Transfer Capacitance	f = 1MHz		220		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		370		
$T_{r}$	Rise Time	$V_{GE} = 15V$		40		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 75A$		650		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 10\Omega$		180		1
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		400		
$T_{r}$	Rise Time	$V_{GE} = 15V$		50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 75A$		800		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 6.8\Omega$		300		
Eon	Turn-on Switching Energy	$V_{GE} = 15V  V_{Bus} = 900V$ $T_j = 125^{\circ}C$		24		m I
$E_{\text{off}}$	Turn-off Switching Energy	$I_C = 75A$ $R_G = 6.8\Omega$ $T_j = 125^{\circ}C$		23.5		mJ

## Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Test Conditions		Тур	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1700			V
$I_{RM}$	Maximum Reverse Leakage Current	$V_{R}=1700V$	$T_j = 25$ °C			250	μA
1 <sub>RM</sub>		V <sub>R</sub> -1700 V	$T_j = 125$ °C			500	μΛ
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		75		A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 75A$	$T_j = 25$ °C		1.8	2.2	V
<b>V</b> F	Blode I of ward Voluge		$T_{i} = 125^{\circ}C$		1.9		,
$t_{rr}$	Reverse Recovery Time	$I_F = 75A$ $V_R = 900V$ $di/dt = 800A/\mu s$	$T_j = 25^{\circ}C$		385		ns
чт	Reverse Recovery Time		$T_{j} = 125^{\circ}C$		490		113
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25^{\circ}C$		19		μС
Qrr	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		31		μ
Е	D	·	$T_j = 25$ °C		9		mJ
$E_{r}$	Reverse Recovery Energy		$T_{i} = 125^{\circ}C$		17.5		1113



### Thermal and package characteristics

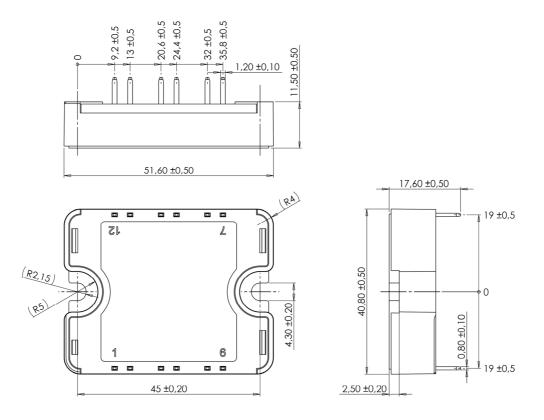
Symbol	Characteristic			Min	Тур	Max	Unit
$R_{\text{thJC}}$	Junction to Case Thermal Resistance IGBT Diode	IGBT			0.27	°C/W	
		Diode			0.5	C/ W	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	
$T_{STG}$	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature	-40		100			
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					80	g

## $Temperature \ sensor \ NTC \ (\text{see application note APT0406 on www.microsemi.com for more information}). \\$

Symbol	Characteristic	Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$
 
$$R_{T}: \text{ Thermistor value at T}$$

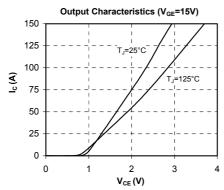
## SP1 Package outline (dimensions in mm)

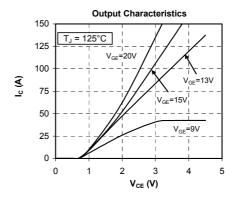


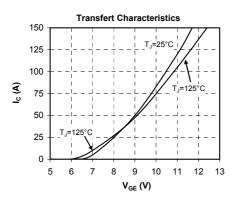
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

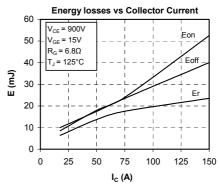


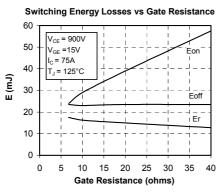
### **Typical Performance Curve**

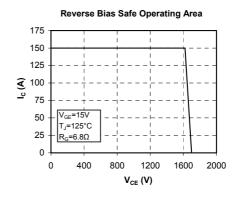


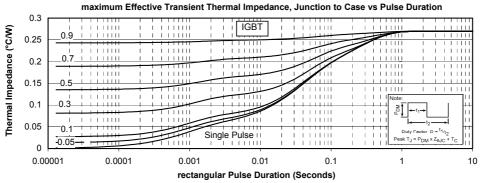




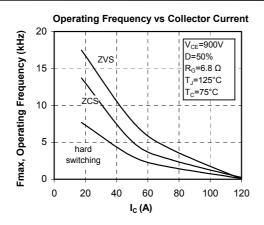


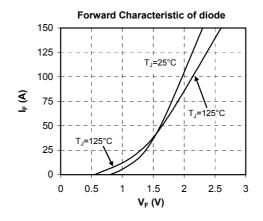


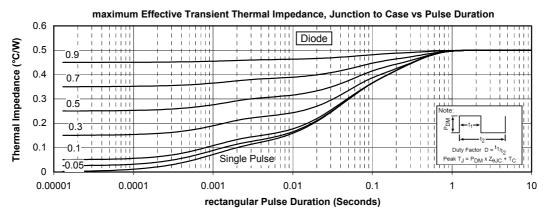












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